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RE: *U.S. Patent Application Serial No.: 10/624,712*  
*Entitled "TECHNIQUE FOR FORMING CONTACTS FOR BURIED*  
*DOPED REGIONS IN A SEMICONDUCTOR DEVICE"*  
*Inventors: Ralv van Benthum and Manfred Horstmann*

Dear Sir or Madam:

Attached is the Fee(s) Transmittal (PTOL-85) for the above-referenced application. The Issue Fee was previously submitted via electronic filing on April 7, 2006. However, PTOL-85 was not uploaded. In order for the Assignee and our firm name to be printed on the Original Letters Patent, we are submitting PTOL-85 for this application.

If you have any questions, please do not hesitate to contact the undersigned attorney.

Respectfully submitted,

Date: May 2, 2006

/J. Mike Amerson/

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